TOSHIBA Field Effect Transistor with Built-in Schottky Barrier Diode Silicon N-Channel MOS Type (U-MOS V-H)

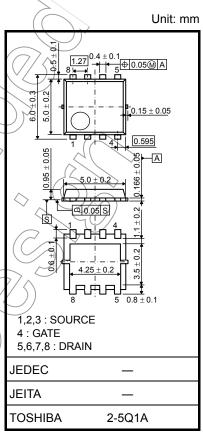
TPCA8A04-H

High Efficiency DC-DC Converter Applications Notebook PC Applications Portable Equipment Applications

- Built-in a schottky barrier diode
 Low forward voltage: V_{DSF} = -0.6 V (max)
- · High-speed switching
- Small gate charge: Q_{SW} = 13.4 nC (typ.)
- Low drain-source ON-resistance: $R_{DS (ON)} = 2.3 \text{ m}\Omega \text{ (typ.)}$
- High forward transfer admittance: $|Y_{fs}| = 127 \text{ S (typ.)}$
- Low leakage current: I_{DSS} = 100 μ A (max) (V_{DS} = 30 V)
- Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_D = 1 mA)

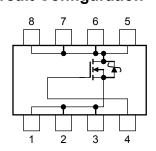
Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		V _{DSS} <	30	y	
Drain-gate voltage (R _{GS} = 20 kΩ)		V _{DGR}	30	< <u>/</u>	
Gate-source voltage		V _{GS} S	±20	V	
Drain current	DC (Note 1)	t D	44	\ A	
	Pulsed (Note 1)	((I _{DP}	132		
Drain power dissipation	on (Tc=25°C)		45 W		
Drain power dissipation (t = 10 s) (Note 2a)		₽ D	2.8	W	
Drain power dissipation (t=10.s) (Note 2b)		PD	1.6	W	
Single-pulse avalanche energy (Note 3)		EAS	252	mJ	
Avalanche current		IAR	44	Α	
Repetitive avalanche energy (Tc=25°C) (Note 4)		EAR	3.32	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature	range	T _{stg}	-55 to 150	°C	



Weight: 0.069 g (typ.)

Circuit Configuration



Note: For Notes 1 to 4, refer to the next page.

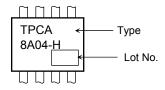
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc=25°C)	R _{th (ch-c)}	2.78	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2a)	R _{th (ch-a)}	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	78.1	°C/W

Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

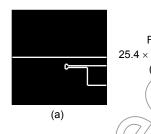
Note 2: (a) Device mounted on a glass-epoxy board (a)

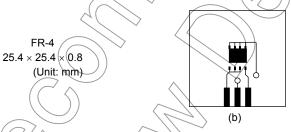
(b) Device mounted on a glass-epoxy board (b)

FR-4

 $25.4\times25.4\times0.8$

(Unit: mm)





Note 3: $V_{DD} = 24 \text{ V}$, $T_{Ch} = 25^{\circ}\text{C}$ (initial), L = 0.1 mH, $R_G \neq 25^{\circ}\Omega$, $I_{AR} = 44 \text{ A}$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: * Weekly code: (Three digits)

Week of manufacture

(01) for first week of year, continuing up to 52 or 53)

Year of manufacture

(The last digit of the calendar year)

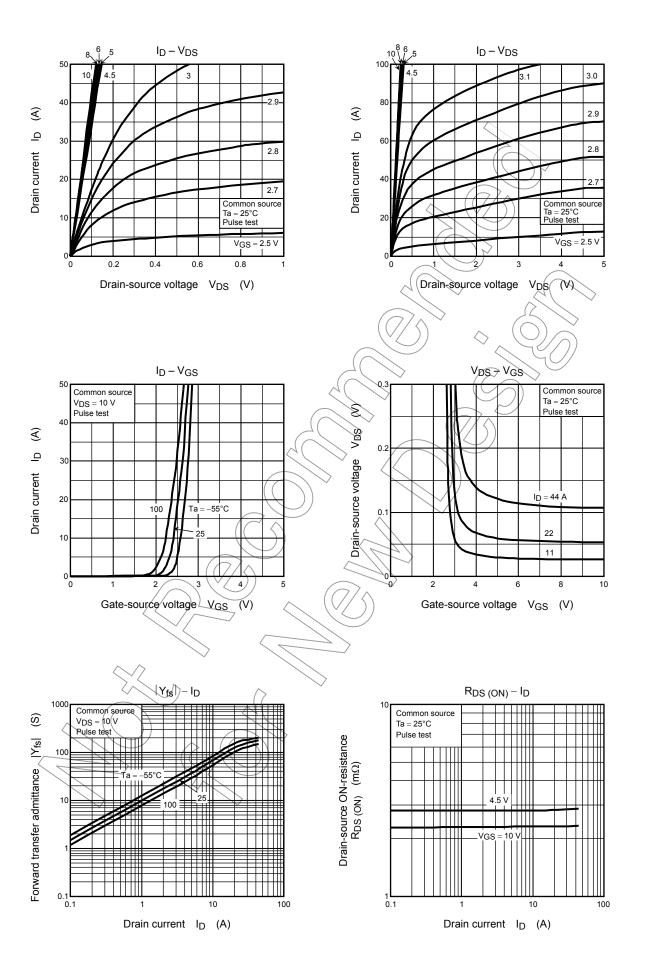
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Electrical Characteristics (Ta = 25°C)

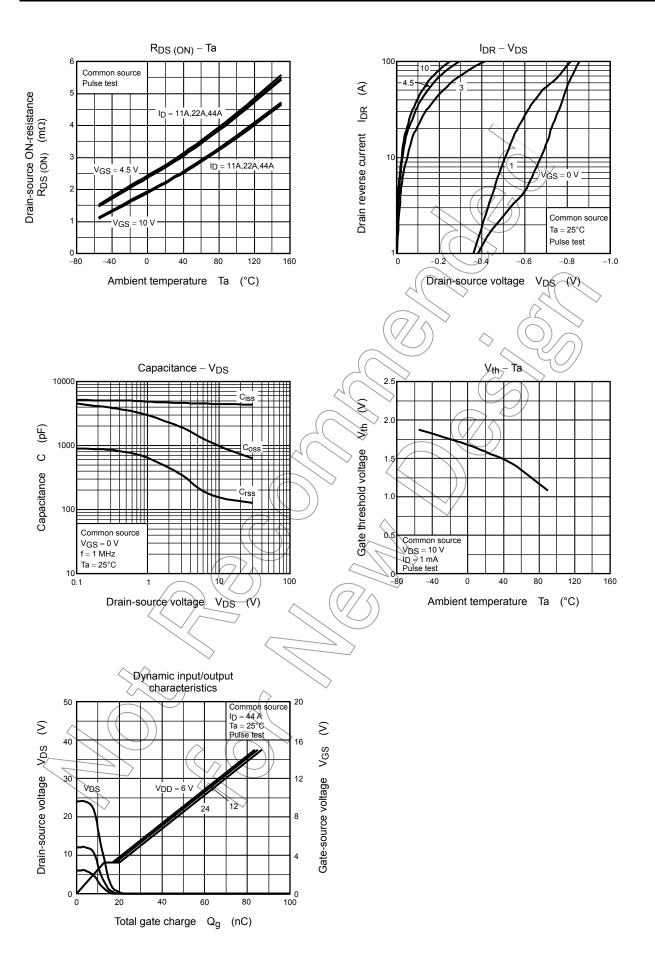
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	nt	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V		_	100	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_	_	V
		V _{(BR) DSX}	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	15	_	_	
Gate threshold vo	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	1.3) / _	2.3	V
Drain source ON	ragiatanaa	_	V _{GS} = 4.5 V, I _D = 22 A	<u> </u>	2.9	4.1	m0
Drain-source ON-resistance		R _{DS} (ON)	V _{GS} = 10 V, I _D = 22 A))	2.3	3.2	mΩ
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 22 A	64	127	_	S
Input capacitance	•	C _{iss}		_	4400	5700	
Reverse transfer	capacitance	C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	180	270	pF
Output capacitan	ce	Coss			990	\nearrow	
Gate resistance		rg	V _{DS} = 10 V, V _{GS} = 0 V, f = 5 MHz	-6	1.0) 1.5	Ω
Switching time	Rise time	t _r	10 V T In = 22 A	7	4.9) _	
	Turn-on time	t _{on}	V _{GS} 10 V I _D = 22 A V _{OUT} G	7(5)	15	_	no
	Fall time	t _f	4.7.7.4 W 98.0.0 W 1.0.0 W 1.0		8.3	_	ns
	Turn-off time	t _{off}	Duty ≤ 1%, t _W = 10 μs	_	57	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 44 \text{ A}$	_	59	_	
			$V_{DD} \approx 24 \text{ V}, V_{GS} = 5 \text{ V}, V_{D} \neq 44 \text{ A}$	_	30		
Gate-source char	ge 1 /	Q _{gs1}		_	13	_	nC
Gate-drain ("Miller") charge		Q _{gd}	$V_{DD} \approx 24 V_{VGS} = 10 V_{DD} = 44 A$	_	7.0	_	
Gate switch charg	ge ((//	Q _{SW}			13.4		

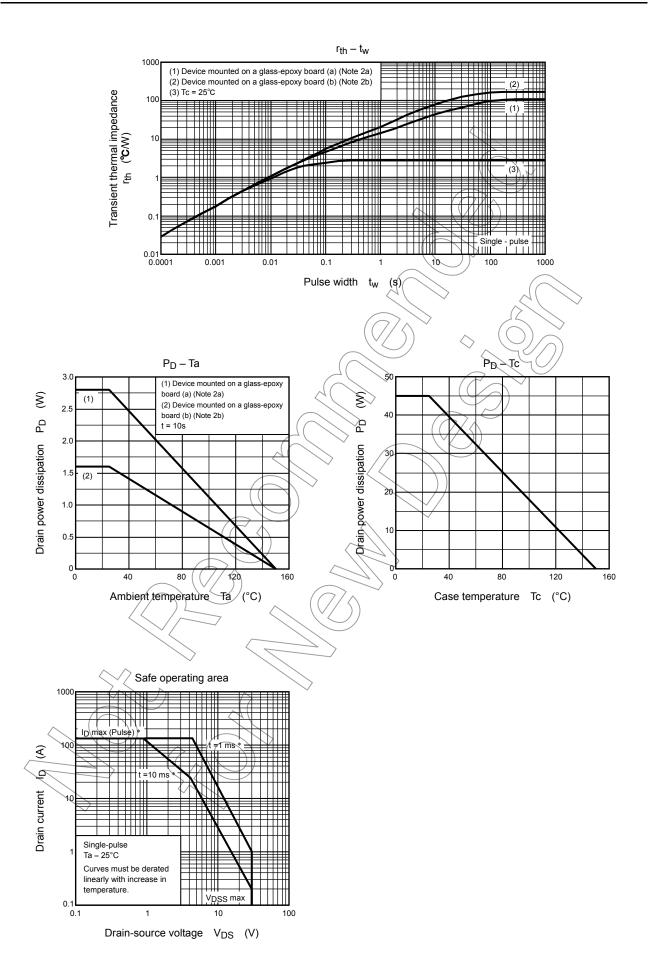
Source-Drain Ratings and Characteristics (Ta = 25°C)

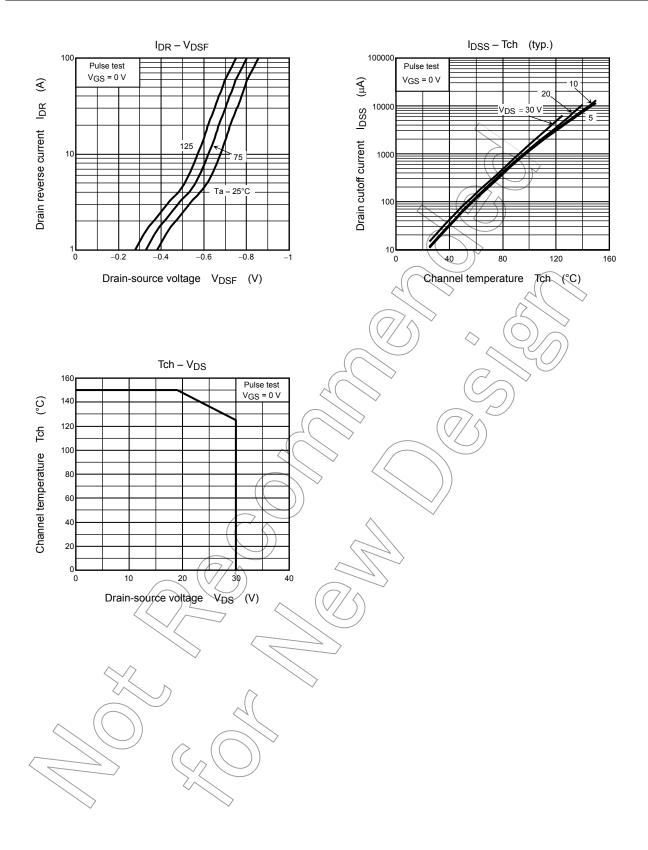
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1)	I _{DRP}	<u> </u>	_	_	132	Α
Forward voltage/diode)	V _{DSF}	I _{DR} = 1 A, V _{GS} = 0 V	_	- 0.4	- 0.6	V
Forward voltage (diode)		$I_{DR} = 44 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	- 1.2	V



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